











TPS54302

ZHCSF83A - MAY 2016-REVISED MAY 2016

TPS54302 4.5V 至 28V 输入电压、3A 输出电流、EMI 友好型 同步降压转换器

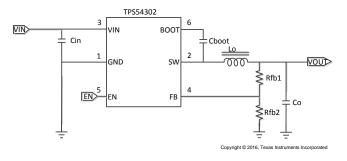
1 特性

- 4.5V 至 28V 宽输入电压范围
- 集成 85mΩ 和 40 mΩ 金属氧化物半导体场效应晶体管 (MOSFET),持续输出电流为 3A
- 关断电流低至 2μA, 静态电流为 45μA
- 内部 5ms 软启动
- 400kHz 固定开关频率
- 扩展频谱,可减少电磁干扰 (EMI)
- 高级 Eco-mode™脉冲跳跃
- 峰值电流模式控制
- 内部环路补偿
- 采用断续模式为两个 MOSFET 提供过流保护
- 过压保护
- 热关断
- 小外形尺寸晶体管 (SOT)-23 (6) 封装

2 应用

- 12V 和 24V 分布式电源总线供电
- 工业应用
 - 白色家电
- 消费类应用
 - 音频
 - 机顶盒 (STB)、数字电视 (DTV)
 - 打印机

简化电路原理图



3 说明

TPS54302 是一款输入电压范围为 4.5V 至 28V 的 3A 同步降压转换器。该器件包含两个集成式开关场效应晶体管 (FET) 并且具备内部回路补偿和 5ms 内部软启动功能,可降低组件数。

通过集成 MOSFET 并采用 SOT-23 封装,TPS54302 获得了高功率密度,并且在印刷电路板 (PCB) 上的占用空间非常小。

高级 Eco-mode 实现以最大限度提高了轻负载效率并降低了功率损耗。

TPS54302 中引入了扩展频谱操作以降低 EMI。

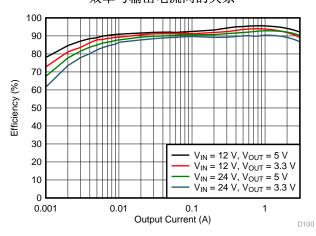
高侧 MOSFET 上的逐周期电流限制功能可在过载条件下保护转换器并通过防止电流失控的低侧 MOSFET 续流电流限制功能实现功能增强。当过流持续时间超出预设时间时,将触发断续模式保护功能。

器件信息(1)

器件型号	封装	封装尺寸(标称值)
TPS54302	SOT-23(6)	1.60mm x 2.90mm

(1) 要了解所有可用封装,请见数据表末尾的可订购产品附录。

效率与输出电流间的关系

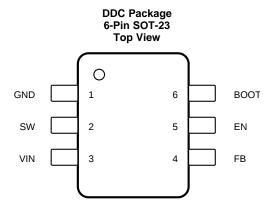




2	特性	1		7.3 Feature Description	
_	应用	1		7.4 Device Functional Modes	
3	说明	1	8	Application and Implementation	
4	修订历史记录	2		8.1 Application Information	
5	Pin Configuration and Functions	3		8.2 Typical Application	
6	Specifications		9	Power Supply Recommendations	20
	6.1 Absolute Maximum Ratings		10	Layout	21
	6.2 ESD Ratings			10.1 Layout Guidelines	
	6.3 Recommended Operating Conditions			10.2 Layout Example	
	6.4 Thermal Information	4	11	器件和文档支持	22
	6.5 Electrical Characteristics	5		11.1 社区资源	<u>22</u>
	6.6 Timing Requirements	5		11.2 商标	
	6.7 Typical Characteristics	6		11.3 静电放电警告	
7	Detailed Description	8		11.4 Glossary	
	7.1 Overview	8	12	机械、封装和可订购信息	22
	7.2 Functional Block Diagram	8			
. <u>1</u>	多订历史记录				



5 Pin Configuration and Functions



Pin Functions

PI	N	TYPE(1)	DESCRIPTION
NAME	NO.	I I PE\"	DESCRIPTION
воот	6	0	Supply input for the high-side NFET gate drive circuit. Connect a 0.1 - μF capacitor between BOOT and SW pins.
EN	5	ı	This pin is the enable pin. Float the EN pin to enable.
FB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider.
GND	1	_	Ground pin Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	0	Switch node connection between high-side NFET and low-side NFET.
VIN	3	_	Input voltage supply pin. The drain terminal of high-side power NFET.

⁽¹⁾ O = Output; I = Input



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		N	IIN	MAX	UNIT
Input voltage range, V _I	VIN	_	0.3	30	V
	EN	_	0.3	7	V
	FB	_	0.3	7	V
	BOOT-SW	_	0.3	7	V
Output voltage range, VO	SW	_	0.3	30	V
	SW (20 ns transient)		-5	30	V
Operating junction temperature	, T _J	-	40	150	°C
Storage temperature range, T _s	g	-	65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\/	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
		VIN	4.5	28	V
V_{I}	Input voltage range	EN	-0.1	7	V
		FB	-0.1	7	V
	Output valtage games	BOOT-SW	-0.1	7	V
Vo	Output voltage range	SW	-0.1	28	V
TJ	T _J Operating junction temperature		-40	125	°C

6.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	DDC (SOT-23)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	87.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	35.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	14.4	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	14.2	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. $T_J = -40$ °C to +125°C, $V_{IN} = 4.5$ V to 28 V, (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT SUPP	LY					
V _{IN}	Input voltage range		4.5		28	V
IQ	Non switching quiescent current	EN =5 V, VFB = 1 V		45		μΑ
I _{OFF}	Shut down current	EN = GND		2		μΑ
	\(\text{\tinx{\tint{\texi{\text{\text{\text{\text{\text{\text{\text{\text{\text{\text{\tinx{\tint{\text{\tint{\text{\tinx{\tint{\text{\tinx{\tint{\text{\tinx{\tint{\tint{\tint{\text{\tinx{\tint{\text{\tinx{\tint{\tex{\tinx{\tint{\text{\tinx{\tint{\text{\tinx{\text{\text{\text{\text{\tinx{\tint{\tinx{\tin	Rising V _{IN}	3.8	4.1	4.4	V
V _{IN(UVLO)}	VIN under voltage lockout	Falling V _{IN}	3.3	3.6	3.9	V
, ,	Hysteresis		400	480	560	mV
ENABLE (EN	PIN)					
V _(EN_RISING)		Rising		1.21	1.28	V
V _(EN_FALLING)	Enable threshold	Falling	1.1	1.19		V
I _(EN INPUT)	Input current	V _{EN} = 1 V		0.7		μΑ
I _(EN HYS)	Hysteresis current	V _{EN} = 1.5 V		1.55		μΑ
FEEDBACK A	AND ERROR AMPLIFIER					
V_{FB}	Feedback Voltage	V _{IN} = 12 V	0.581	0.596	0.611	V
PULSE SKIP	MODE					
I _(SKIP) ⁽¹⁾	Pulse skip mode peak inductor current threshold	V _{IN} = 12 V, V _{OUT} = 5 V, L = 10 μH		500		mA
POWER STA	GE					
R _(HSD)	High-side FET on resistance	$T_A = 25^{\circ}C, V_{BST} - SW = 6 V$		85		mΩ
R _(LSD)	Low-side FET on resistance	T _A = 25°C, V _{IN} = 12		40		mΩ
CURRENT LI	MIT					
I _(LIM_HS)	High side current limit	Maximum inductor peak current	4	5	5.9	Α
I _(LIM_LS)	Low side source current limit	Maximum inductor valley current	3.1	4	5.5	Α
OSCILLATOR	₹					
F _{sw}	Centre switching frequency		290	400	510	kHz
OVER TEMPI	ERATURE PROTECTION					
	Rising temperature			165		°C
Thermal Shutdown ⁽¹⁾	Hysteresis			10		°C
Chataowii	Hiccup time			32768		Cycles

⁽¹⁾ Not production tested

6.6 Timing Requirements

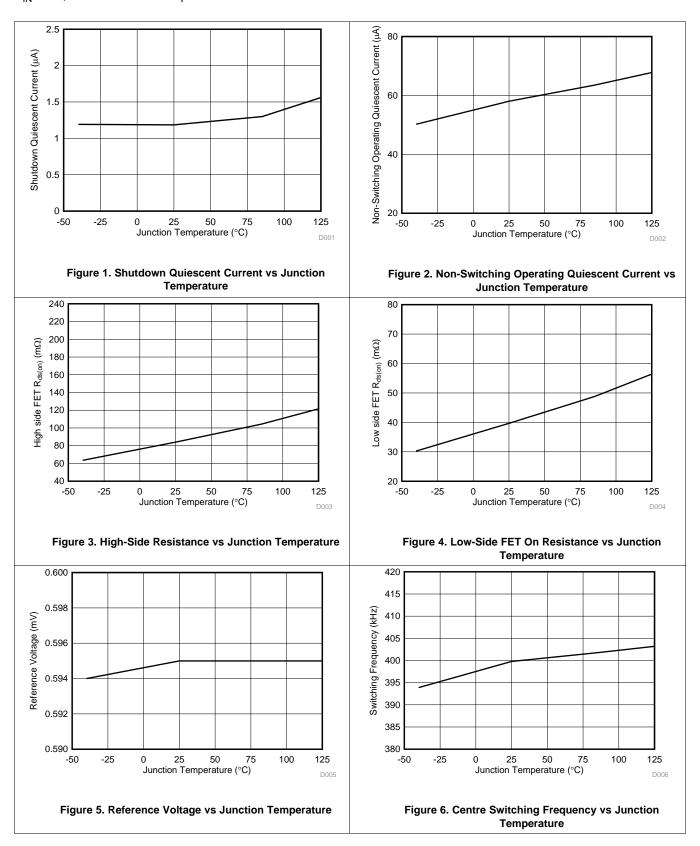
			MIN	TYP	MAX	UNIT
OVER CURRENT PROTECTION						
t _{HIC_WAIT}	Hiccup wait time			512		Cycles
t _{HIC_RESTART}	Hiccup time before restart			16384		Cycles
t _{SS}	Soft-start time			5		ms
ON TIME CONTROL						
t _{MIN_ON} ⁽¹⁾	Minimum on time, measured at 90% to 90% and 1-A loading			110		ns

⁽¹⁾ Not production tested

TEXAS INSTRUMENTS

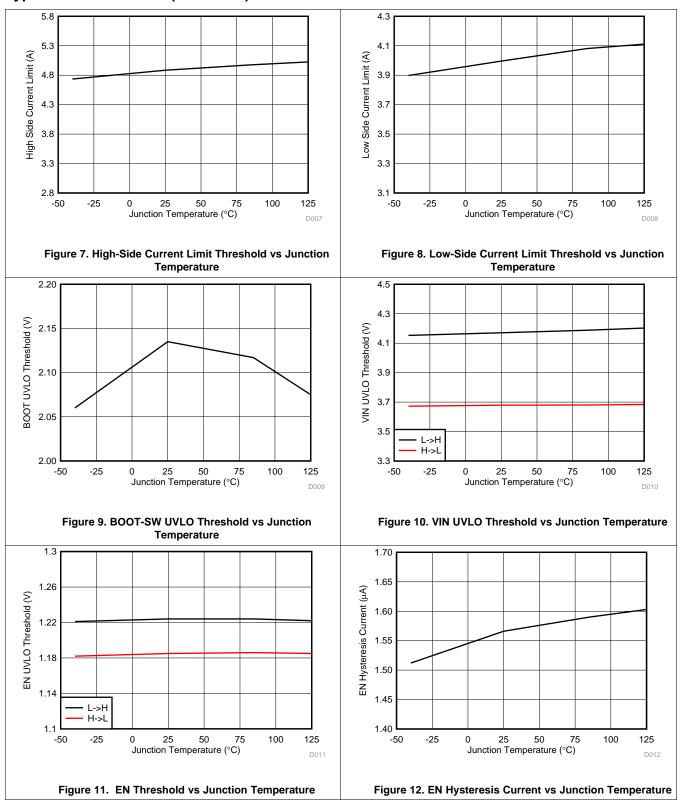
6.7 Typical Characteristics

V_{IN} = 12, unless otherwise specified





Typical Characteristics (continued)



7 Detailed Description

7.1 Overview

The device is a 28-V, 3-A, synchronous step-down (buck) converter with two integrated n-channel MOSFETs. To improve performance during line and load transients the device implements a constant-frequency, peak current mode control which reduces output capacitance. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

The TPS54302's switching frequency is fixed to 400 kHz.

The TPS54302 starts switching at VIN equal to 4.5 V. The operating current is 45 μ A typically when not switching and under no load. When the device is disabled, the supply current is 2 μ A typically.

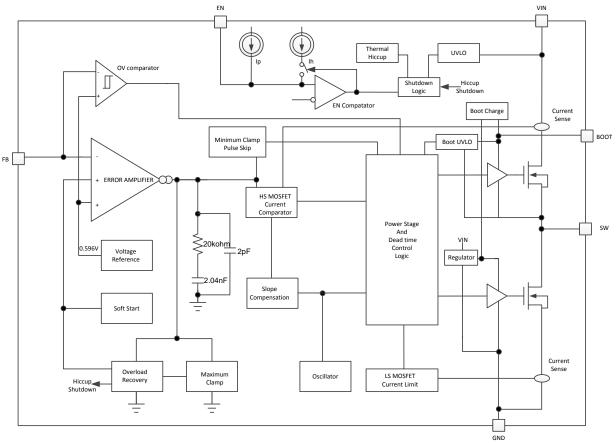
The integrated 85-m Ω high-side MOSFET and 40-m Ω low-side MOSFET allow for high efficiency power supply designs with continuous output currents up to 3 A.

The TPS54302 reduces the external component count by integrating the boot recharge diode. The bias voltage for the integrated high-side MOSFET is supplied by an external capacitor on the BOOT to PH pins. The boot capacitor voltage is monitored by an UVLO circuit and will turn the high-side MOSFET off when the voltage falls below a preset threshold of 2.1 V typically.

The device minimizes excessive output overvoltage transients by taking advantage of the overvoltage comparator. When the regulated output voltage is greater than 108% of the nominal voltage, the overvoltage comparator is activated, and the high-side MOSFET is turned off and masked from turning on until the output voltage is lower than 104%.

The TPS54302 device has internal 5-ms soft-start time to minimize inrush currents.

7.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated



7.3 Feature Description

7.3.1 Fixed-Frequency PWM Control

The device uses a fixed-frequency, peak current-mode control. The output voltage is compared through external resistors on the FB pin to an internal voltage reference by an error amplifier. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is compared to the current of the high-side power switch. When the power-switch current reaches the error amplifier output voltage level, the high side power switch is turned off and the low-side power switch is turned on. The error amplifier output voltage increases and decreases as the output current increases and decreases. The device implements a current-limit by clamping the error amplifier voltage to a maximum level and also implements a minimum clamp for improved transient-response performance.

7.3.2 Pulse Skip Mode

The TPS54302 is designed to operate in pulse skipping mode at light load currents to boost light load efficiency. When the peak inductor current is lower than 500 mA typically, the device enters pulse skipping mode. When the device is in pulse skipping mode, the error amplifier output voltage is clamped which prevents the high side integrated MOSFET from switching. The peak inductor current must rise above 500 mA and exit pulse skip mode. Since the integrated current comparator catches the peak inductor current only, the average load current entering pulse skipping mode varies with the applications and external output filters.

7.3.3 Error Amplifier

The device has a trans-conductance amplifier as the error amplifier. The error amplifier compares the FB voltage to the lower of the internal soft-start voltage or the internal 0.596-V voltage reference. The transconductance of the error amplifier is 240 μ A/V typically. The frequency compensation components are placed internal between the output of the error amplifier and ground.

7.3.4 Slope Compensation and Output Current

The device adds a compensating ramp to the signal of the switch current. This slope compensation prevents sub-harmonic oscillations as the duty cycle increases. The available peak inductor current remains constant over the full duty-cycle range.

7.3.5 Enable and Adjusting Undervoltage Lockout

The EN pin provides electrical on and off control of the device. When the EN pin voltage exceeds the threshold voltage, the device begins operation. If the EN pin voltage is pulled below the threshold voltage, the regulator stops switching and enters the low-quiescent (IQ) state.

The EN pin has an internal pullup-current source which allows the user to float the EN pin to enable the device. If an application requires control of the EN pin, use open-drain or open-collector output logic to interface with the pin.

The device implements internal undervoltage-lockout (UVLO) circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO threshold has a hysteresis of 480 mV.

If an application requires a higher UVLO threshold on the VIN pin, then the EN pin can be configured as shown in Figure 13. When using the external UVLO function, setting the hysteresis at a value greater than 500 mV is recommended.

The EN pin has a small pull-up current, Ip, which sets the default state of the pin to enable when no external components are connected. The pull-up current is also used to control the voltage hysteresis for the UVLO function because it increases by Ih when the EN pin crosses the enable threshold. Use Equation 1 and Equation 2 to calculate the values of R4 and R5 for a specified UVLO threshold.



Feature Description (continued)

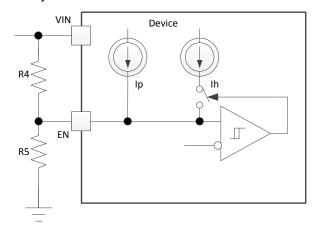


Figure 13. Adjustable VIN Undervoltage Lockout

$$R4 = \frac{V_{START} \left(\frac{V_{ENfalling}}{V_{ENrising}} \right) - V_{STOP}}{I_{p} \left(1 - \frac{V_{ENfalling}}{V_{ENrising}} \right) + I_{h}}$$

$$(1)$$

Where:

$$\begin{split} I_p &= 0.7 \ \mu\text{A} \\ I_h &= 1.55 \ \mu\text{A} \\ V_{\text{ENfalling}} &= 1.19 \ \text{V} \\ V_{\text{ENrising}} &= 1.22 \ \text{V} \\ R5 &= \frac{\text{R4} \times \text{V}_{\text{ENfalling}}}{\text{V}_{\text{STOP}} - \text{V}_{\text{ENfalling}} + \text{R4} \left(I_p + I_h \right)} \end{split}$$

7.3.6 Safe Startup into Pre-Biased Outputs

The device has been designed to prevent the low-side MOSFET from discharging a pre-biased output. During monotonic pre-biased startup, both high-side and low-side MOSFETs are not allowed to be turned on until the internal soft-start voltage is higher than FB pin voltage.

7.3.7 Voltage Reference

The voltage reference system produces a precise ±2.5% voltage-reference over temperature by scaling the output of a temperature stable bandgap circuit. The typical voltage reference is designed at 0.596 V.

7.3.8 Adjusting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. It is recommended to use divider resistors with 1% tolerance or better. Start with 100 k Ω for the upper resistor divider, use Equation 3 to calculate the output voltage. To improve efficiency at light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable.

$$V_{out} = V_{ref} \times \left[\frac{R2}{R3} + 1 \right]$$
 (3)

7.3.9 Internal Soft-Start

The TPS54302 device uses the internal soft-start function. The internal soft start time is set to 5 ms typically.



Feature Description (continued)

7.3.10 Bootstrap Voltage (BOOT)

The TPS54302 has an integrated boot regulator and requires a 0.1-µF ceramic capacitor between the BOOT and SW pins to provide the gate drive voltage for the high-side MOSFET. A ceramic capacitor with an X7R or X5R grade dielectric is recommended because of the stable characteristics over temperature and voltage. To improve drop out, the TPS54302 is designed to operate at 100% duty cycle as long as the BOOT to SW pin voltage is greater than 2.1 V typically.

7.3.11 Overcurrent Protection

The device is protected from overcurrent conditions by cycle-by-cycle current limiting on both the high-side MOSFET and the low-side MOSFET.

7.3.11.1 High-Side MOSFET Overcurrent Protection

The device implements current mode control which uses the internal COMP voltage to control the turn off of the high-side MOSFET and the turn on of the low-side MOSFET on a cycle-by-cycle basis. During each cycle, the switch current and the current reference generated by the internal COMP voltage are compared. When the peak switch current intersects the current reference the high-side switch turns off.

7.3.11.2 Low-Side MOSFET Overcurrent Protection

While the low-side MOSFET is turned on, the conduction current is monitored by the internal circuitry. During normal operation the low-side MOSFET sources current to the load. At the end of every clock cycle, the low-side MOSFET sourcing current is compared to the internally set low-side sourcing current-limit. The inductor valley current is exceeded the low-side source current limit, the high-side MOSFET does not turn on and the low-side MOSFET stays on for the next cycle. The high-side MOSFET turns on again when the inductor valley current is below the low-side sourcing current-limit at the start of a cycle as shown in Figure 14.

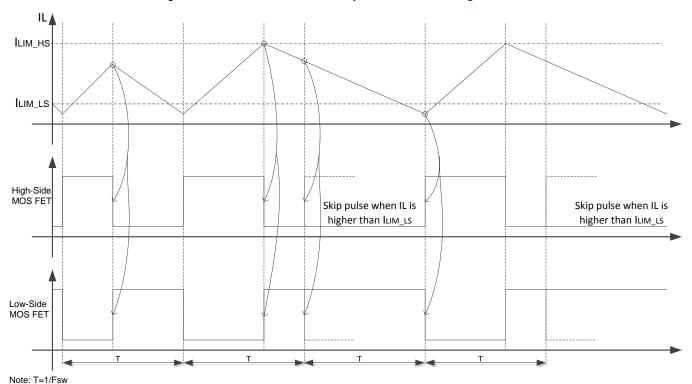


Figure 14. Overcurrent Protection for Both MOSFETs

Furthermore, if an output overload condition occurs for more than the hiccup wait time, which is programmed for 512 switching cycles, the device shuts down and restarts after the hiccup time of 16384 cycles. The hiccup mode helps to reduce the device power dissipation under severe overcurrent conditions.



Feature Description (continued)

7.3.12 Spread Spectrum

In order to reduce EMI, the TPS54302 introduces frequency spread spectrum. The jittering span is $\pm 6\%$ of the switching frequency with 1/512 swing frequency.

7.3.13 Output Overvoltage Protection (OVP)

The TPS54302 incorporates an overvoltage transient protection (OVTP) circuit to minimize output voltage overshoot when recovering from output fault conditions or strong unload transients. The OVTP circuit includes an overvoltage comparator to compare the FB pin voltage and internal thresholds. When the FB pin voltage goes above $108\% \times \text{Vref}$, the high-side MOSFET is forced off. When the FB pin voltage falls below $104\% \times \text{Vref}$, the high-side MOSFET is enabled again.

7.3.14 Thermal Shutdown

The internal thermal-shutdown circuitry forces the device to stop switching if the junction temperature exceeds 165°C typically. When the junction temperature drops below 155°C typically, the internal thermal-hiccup timer begins to count. The device reinitiates the power-up sequence after the built-in thermal-shutdown hiccup time (32768 cycles) is over.

7.4 Device Functional Modes

7.4.1 Normal Operation

When the input voltage is above the UVLO threshold, the TPS54302 can operate in their normal switching modes. Normal continuous conduction mode (CCM) occurs when inductor peak current is above 0 A. In CCM, the TPS54302 operates at a fixed frequency.

7.4.2 Eco-mode™ Operation

The device is designed to operate in high-efficiency pulse-skipping mode under light load conditions. Pulse skipping initiates when the switch current falls to 500 mA typically. During pulse skipping, the low-side FET turns off when the switch current falls to 0 A. The switching node (the SW pin) waveform takes on the characteristics of discontinuous conduction mode (DCM) operation and the apparent switching frequency decreases. As the output current decreases, the perceived time between switching pulses increases.



8 Application and Implementation

NOTE

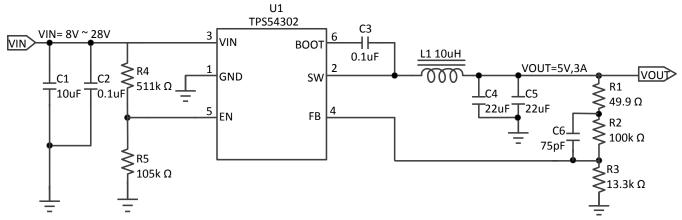
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS54302 is typically used as a step down converter, which converts an input voltage from 8 V - 28 V to a fixed output voltage of 5 V.

8.2 Typical Application

8.2.1 TPS54302 8-V to 28-V Input, 5-V Output Converter



Copyright © 2016, Texas Instruments Incorporated

Figure 15. 5-V, 3-A Reference Design

8.2.2 Design Requirements

For this design example, use the parameters in Table 1.

Table 1. Design Parameters

PARAMETER	VALUE
Input voltage range	8 V to 28 V
Output voltage	5 V
Output current	3 A
Transient response, 1.5-A load step	$\Delta V_{OUT} = \pm 5 \%$
Input ripple voltage	400 mV
Output voltage ripple	30 m√pp
Switching frequency	400 kHz



8.2.3 Detailed Design Procedure

8.2.3.1 Input Capacitor Selection

The device requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 μ F is recommended for the decoupling capacitor. An additional 0.1- μ F capacitor (C2) from VIN to GND is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

Use Equation 4 to calculate the input ripple voltage (ΔV_{IN}).

$$\Delta V_{IN} = \frac{I_{OUT(MAX)} \times 0.25}{C_{BULK} \times f_{sw}} + \left(I_{OUT(MAX)} \times ESR_{MAX}\right)$$
(4)

where:

C_{BULK} is the bulk capacitor value

f_{SW} is the switching frequency

 $I_{\text{OUT}(\text{MAX})}$ is the maximum loading current

ESR_{MAX} is maximum series resistance of the bulk capacitor

The maximum RMS (root mean square) ripple current must also be checked. For worst case conditions, use Equation 5 to calculate $I_{CIN(RMS)}$.

$$I_{CIN(RMS)} = \frac{I_{O(MAX)}}{2} \tag{5}$$

The actual input-voltage ripple is greatly affected by parasitic associated with the layout and the output impedance of the voltage source. Design Requirements show the actual input voltage ripple for this circuit which is larger than the calculated value. This measured value is still below the specified input limit of 400 mV. The maximum voltage across the input capacitors is VIN (MAX) + Δ VIN/2. The selected bypass capacitor is rated for 35 V and the ripple current capacity is greater than 2 A. Both values provide ample margin. The maximum ratings for voltage and current must not be exceeded under any circumstance.

8.2.3.2 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the BOOT to SW pin for proper operation. It is recommended to use a ceramic capacitor.

8.2.3.3 Output Voltage Set Point

The output voltage of the TPS54302 device is externally adjustable using a resistor divider network. In the application circuit of Figure 15, this divider network is comprised of R2 and R3. Use Equation 6 and Equation 7 to calculate the relationship of the output voltage to the resistor divider.

$$R3 = \frac{R2 \times V_{ref}}{V_{OUT} - V_{ref}}$$
 (6)

$$V_{out} = V_{ref} \times \left[\frac{R2}{R3} + 1 \right]$$
 (7)

Select a value of R2 to be approximately 100 k Ω . Slightly increasing or decreasing R3 can result in closer output voltage matching when using standard value resistors. In this design, R2 = 100 k Ω and R3 = 13.3 k Ω which results in a 5-V output voltage. The 49.9- Ω resistor, R1, is provided as a convenient location to break the control loop for stability testing.

8.2.3.4 Undervoltage Lockout Set Point

The undervoltage lockout (UVLO) set point can be adjusted using the external-voltage divider network of R4 and R5. R4 is connected between the VIN and EN pins of the TPS54302 device. R5 is connected between the EN and GND pins. The UVLO has two thresholds, one for power up when he input voltage is rising and one for power down or brown outs when the input voltage is falling. For the example design, the minimum input voltage is 8 V, so the start voltage threshold is set to 6.74 V and the stop voltage threshold is set to 5.83 V. Use Equation 1 and Equation 2 to calculate the values for the upper and lower resistor values of R4 and R5.



8.2.3.5 Output Filter Components

Two components must be selected for the output filter, the output inductor (L_O) and C_O.

8.2.3.5.1 Inductor Selection

Use Equation 8 to calculate the minimum value of the output inductor (L_{MIN}).

$$L_{MIN} = \frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{V_{IN(MAX)} \times K_{IND} \times I_{OUT} \times f_{sw}}$$
(8)

Where:

K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current.

In general, the value of K_{IND} is at the discretion of the designer; however, the following guidelines may be used. For designs using low-ESR output capacitors, such as ceramics, a higher K_{IND} can be used. When using higher ESR output capacitors, $K_{IND} = 0.2$ yields better results.

For this design example, use $K_{IND} = 0.35$. The minimum inductor value is calculated as 9.78 μ H. For this design, a close standard value of 10 μ H was selected for L_{MIN} .

For the output filter inductor, the RMS current and saturation current ratings must not be exceeded. Use Equation 9 to calculate the RMS inductor current ($I_{L(RMS)}$).

$$I_{L(MAX)} = \sqrt{I_{OUT(MAX)}^2 + \frac{1}{12} \times \left(\frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT} \right)}{V_{IN(MAX)} \times L_{OUT} \times f_{SW} \times 0.8} \right)^2}$$
(9)

Use Equation 10 to calculate the peak inductor current (I_{I (PK)}).

$$I_{L(PK)} = I_{OUT(MAX)} + \frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{1.6 \times V_{IN(MAX)} \times L_{OUT} \times f_{SW}}$$
(10)

Smaller or larger inductor values can be used depending on the amount of ripple current the designer wants to allow so long as the other design requirements are met. Larger value inductors have lower AC current and result in lower output voltage ripple. Smaller inductor values increase AC current and output voltage ripple.

8.2.3.5.2 Output Capacitor Selection

Consider three primary factors when selecting the value of the output capacitor. The output capacitor determines the modulator pole, the output voltage ripple, and how the regulator responds to a large change in load current. The output capacitance must be selected based on the more stringent of these three criteria.

The desired response to a large change in the load current is the first criterion. The output capacitor must supply the load with current when the regulator cannot. This situation occurs if the desired hold-up times are present for the regulator. In this case, the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator is also temporarily unable to supply sufficient output current if a large, fast increase occurs affecting the current requirements of the load, such as a transition from no load to full load. The regulator usually requires two or more clock cycles for the control loop to notice the change in load current and output voltage and to adjust the duty cycle to react to the change. The output capacitor must be sized to supply the extra current to the load until the control loop responds to the load change. The output capacitance must be large enough to supply the difference in current for 2 clock cycles while only allowing a tolerable amount of drop in the output voltage. Use Equation 11 to calculate the minimum required output capacitance.



$$C_{O} > \frac{2 \times \Delta I_{OUT}}{f_{sw} \times \Delta V_{OUT}}$$
(11)

where:

 ΔI_{OUT} is the change in output current

 f_{SW} is the switching frequency of the regulator

 $\Delta V_{(OUT)}$ b is the allowable change in the output voltage

For this example, the transient load response is specified as a 5% change in the output voltage, V_{OUT} , for a load step of 1.5 A. For this example, $\Delta I_{OUT} = 1.5$ A and $\Delta V_{OUT} = 0.05 \times 5 = 0.25$ V. Using these values results in a minimum capacitance of 30 μ F. This value does not consider the ESR of the output capacitor in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation.

Equation 12 calculates the minimum output capacitance required to meet the output voltage ripple specification. In this case, the maximum output voltage ripple is 30 mV. Under this requirement, Equation 12 yields 10.7 μ F.

$$C_{O} > \frac{1}{8 \times f_{SW}} \times \frac{1}{\frac{V_{OUTripple}}{I_{ripple}}}$$
(12)

where:

 $f_{\rm SW}$ is the switching frequency

V_(OUTripple) is the maximum allowable output voltage ripple

 $I_{(ripple)}$ is the inductor ripple current

Use Equation 13 to calculate the maximum ESR an output capacitor can have to meet the output-voltage ripple specification. Equation 13 indicates the ESR should be less than 29.2 m Ω . In this case, the ESR of the ceramic capacitor is much smaller than 29.2 m Ω .

$$R_{ESR} < \frac{V_{OUTripple}}{I_{ripple}}$$
(13)

The output capacitor can affect the crossover frequency f_o . Considering to the loop stability and effect of the internal parasitic parameters, choose the crossover frequency less than 40 kHz without considering the feed forward capacitor. A simple estimation for the crossover frequency without feed forward capacitor C6 is shown in Equation 14, assuming C_{OUT} has small ESR.

$$f_{o} = \frac{5.1}{V_{OUT} \times C_{OUT}}$$
(14)

Additional capacitance deratings for aging, temperature, and DC bias should be considered which increases this minimum value. For this example, two 22-uF 25-V, X7R ceramic capacitors are used. Capacitors generally have limits to the amount of ripple current they can handle without failing or producing excess heat. An output capacitor that can support the inductor ripple current must be specified. Some capacitor data sheets specify the RMS value of the maximum ripple current. Use Equation 15 to calculate the RMS ripple current that the output capacitor must support. For this application, Equation 15 yields 296 mA for each capacitor.

$$I_{COUT(RMS)} = \frac{1}{\sqrt{12}} \times \left(\frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT} \right)}{V_{IN(MAX)} \times L_{OUT} \times f_{SW} \times N_{C}} \right)$$
(15)



8.2.3.5.3 Feed-Forward Capacitor

The TPS54302 is internally compensated and the internal compensation network is composed of two capacitors and one resister shown on the block diagram. Depending on the V_{OUT} , if the output capacitor C_{OUT} is dominated by low ESR (ceramic types) capacitors, it could result in low phase margin. To improve the phase boost an external feedforward capacitor C6 can be added in parallel with R2. C6 is chosen such that phase margin is boosted at the crossover frequency.

Equation 16 for C6 was tested:

$$C6 = \frac{1}{2\pi f_0} \times \frac{1}{R_2} \tag{16}$$

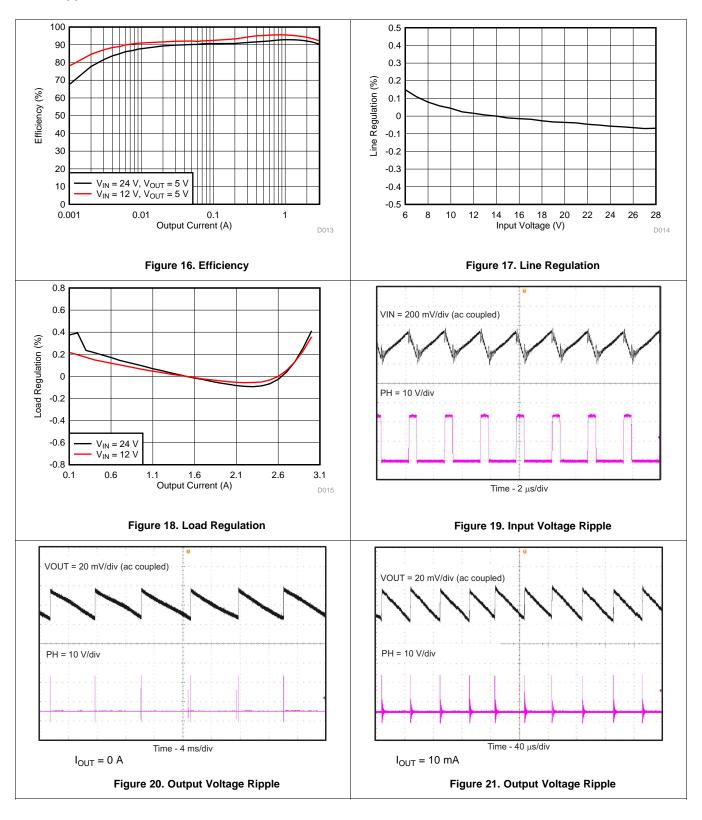
For this design, C6 = 75 pF. C6 is not needed when C_{OUT} has high ESR, and C6 calculated from Equation 16 should be reduced with medium ESR. Table 2 can be used as a starting point.

Table 2. Recommended Component Values

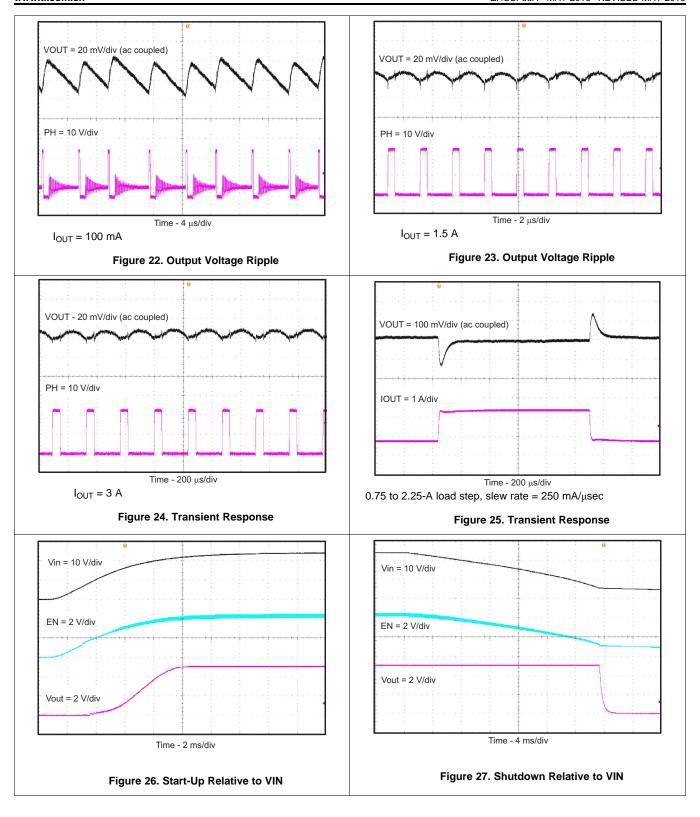
V _{OUT} (V)	L (µH)	C _{OUT} (μF)	R2 (kΩ)	R3 (kΩ)	C8 (pF)
1.8	4.7	66	100	49.9	33
2.5	5.6	66	100	31.6	47
3.3	6.8	44	100	22.1	47
5	10	44	100	13.3	75
12	15	44	100	5.23	100

TEXAS INSTRUMENTS

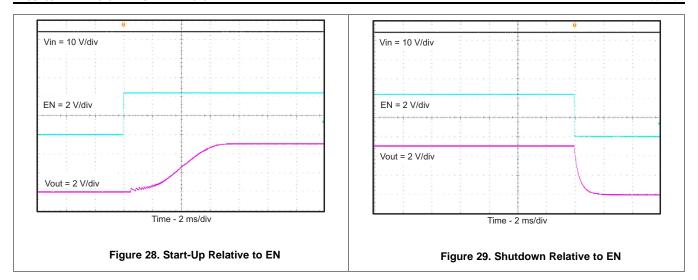
8.2.4 Application Curves











9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 4.5 V and 28 V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of $47~\mu\text{F}$ is a typical choice.



10 Layout

10.1 Layout Guidelines

- VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
- The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- A separate VOUT path should be connected to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
- The trace of the VFB node should be as small as possible to avoid noise coupling.
- The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.

10.2 Layout Example

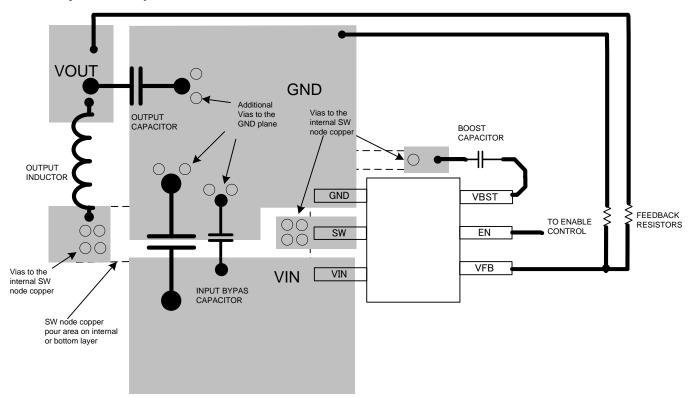


Figure 30. Board Layout



11 器件和文档支持

11.1 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Lise

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.2 商标

Eco-mode, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

11.3 静电放电警告



这些装置包含有限的内置 ESD 保护。 存储或装卸时,应将导线一起截短或将装置放置于导电泡棉中,以防止 MOS 门极遭受静电损伤。

11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本,请查阅左侧的导航栏。

重要声明

德州仪器(TI) 及其下属子公司有权根据 JESD46 最新标准, 对所提供的产品和服务进行更正、修改、增强、改进或其它更改, 并有权根据 JESD48 最新标准中止提供任何产品和服务。客户在下订单前应获取最新的相关信息, 并验证这些信息是否完整且是最新的。所有产品的销售都遵循在订单确认时所提供的TI 销售条款与条件。

TI 保证其所销售的组件的性能符合产品销售时 TI 半导体产品销售条件与条款的适用规范。仅在 TI 保证的范围内,且 TI 认为 有必要时才会使用测试或其它质量控制技术。除非适用法律做出了硬性规定,否则没有必要对每种组件的所有参数进行测试。

TI 对应用帮助或客户产品设计不承担任何义务。客户应对其使用 TI 组件的产品和应用自行负责。为尽量减小与客户产品和应 用相关的风险,客户应提供充分的设计与操作安全措施。

TI 不对任何 TI 专利权、版权、屏蔽作品权或其它与使用了 TI 组件或服务的组合设备、机器或流程相关的 TI 知识产权中授予 的直接或隐含权限作出任何保证或解释。TI 所发布的与第三方产品或服务有关的信息,不能构成从 TI 获得使用这些产品或服 务的许可、授权、或认可。使用此类信息可能需要获得第三方的专利权或其它知识产权方面的许可,或是 TI 的专利权或其它 知识产权方面的许可。

对于 TI 的产品手册或数据表中 TI 信息的重要部分,仅在没有对内容进行任何篡改且带有相关授权、条件、限制和声明的情况 下才允许进行 复制。TI 对此类篡改过的文件不承担任何责任或义务。复制第三方的信息可能需要服从额外的限制条件。

在转售 TI 组件或服务时,如果对该组件或服务参数的陈述与 TI 标明的参数相比存在差异或虚假成分,则会失去相关 TI 组件 或服务的所有明示或暗示授权,且这是不正当的、欺诈性商业行为。TI 对任何此类虚假陈述均不承担任何责任或义务。

客户认可并同意,尽管任何应用相关信息或支持仍可能由 TI 提供,但他们将独力负责满足与其产品及在其应用中使用 TI 产品 相关的所有法律、法规和安全相关要求。客户声明并同意,他们具备制定与实施安全措施所需的全部专业技术和知识,可预见 故障的危险后果、监测故障及其后果、降低有可能造成人身伤害的故障的发生机率并采取适当的补救措施。客户将全额赔偿因 在此类安全关键应用中使用任何 TI 组件而对 TI 及其代理造成的任何损失。

在某些场合中,为了推进安全相关应用有可能对 TI 组件进行特别的促销。TI 的目标是利用此类组件帮助客户设计和创立其特 有的可满足适用的功能安全性标准和要求的终端产品解决方案。尽管如此,此类组件仍然服从这些条款。

TI 组件未获得用于 FDA Class III(或类似的生命攸关医疗设备)的授权许可,除非各方授权官员已经达成了专门管控此类使 用的特别协议。

只有那些 TI 特别注明属于军用等级或"增强型塑料"的 TI 组件才是设计或专门用于军事/航空应用或环境的。购买者认可并同 意,对并非指定面向军事或航空航天用途的 TI 组件进行军事或航空航天方面的应用,其风险由客户单独承担,并且由客户独 力负责满足与此类使用相关的所有法律和法规要求。

TI 己明确指定符合 ISO/TS16949 要求的产品,这些产品主要用于汽车。在任何情况下,因使用非指定产品而无法达到 ISO/TS16949 要求,TI不承担任何责任。

	产品		应用
数字音频	www.ti.com.cn/audio	通信与电信	www.ti.com.cn/telecom
放大器和线性器件	www.ti.com.cn/amplifiers	计算机及周边	www.ti.com.cn/computer
数据转换器	www.ti.com.cn/dataconverters	消费电子	www.ti.com/consumer-apps
DLP® 产品	www.dlp.com	能源	www.ti.com/energy
DSP - 数字信号处理器	www.ti.com.cn/dsp	工业应用	www.ti.com.cn/industrial
时钟和计时器	www.ti.com.cn/clockandtimers	医疗电子	www.ti.com.cn/medical
接口	www.ti.com.cn/interface	安防应用	www.ti.com.cn/security
逻辑	www.ti.com.cn/logic	汽车电子	www.ti.com.cn/automotive
电源管理	www.ti.com.cn/power	视频和影像	www.ti.com.cn/video
微控制器 (MCU)	www.ti.com.cn/microcontrollers		
RFID 系统	www.ti.com.cn/rfidsys		
OMAP应用处理器	www.ti.com/omap		
无线连通性	www.ti.com.cn/wirelessconnectivity	德州仪器在线技术支持社区	www.deyisupport.com

邮寄地址: 上海市浦东新区世纪大道1568 号,中建大厦32 楼邮政编码: 200122 Copyright © 2016, 德州仪器半导体技术(上海)有限公司



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS54302DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4302	Samples
TPS54302DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4302	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





10-Dec-2020

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Jul-2020

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54302DDCR	SOT- 23-THIN	DDC	6	3000	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3
TPS54302DDCT	SOT- 23-THIN	DDC	6	250	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3

www.ti.com 24-Jul-2020

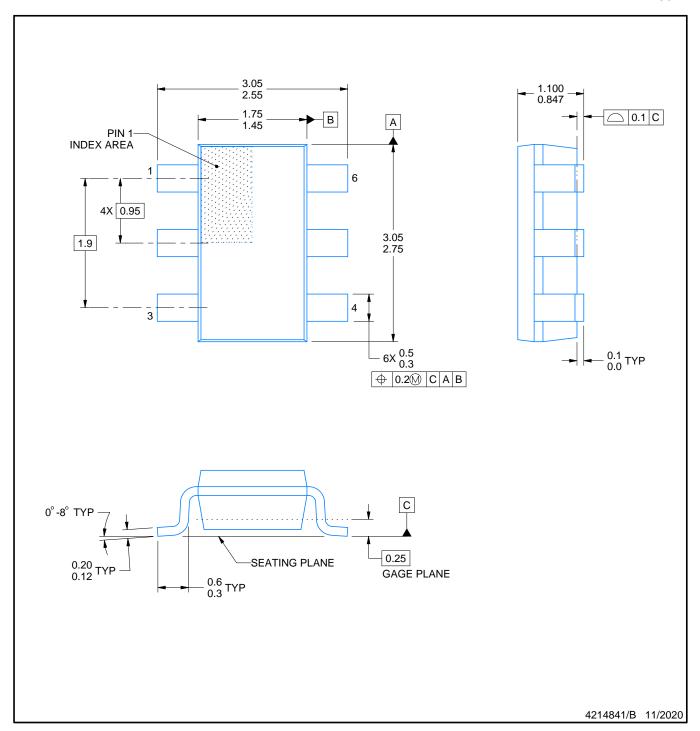


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TPS54302DDCR	SOT-23-THIN	DDC	6	3000	184.0	184.0	19.0	
TPS54302DDCT	SOT-23-THIN	DDC	6	250	184.0	184.0	19.0	



SOT

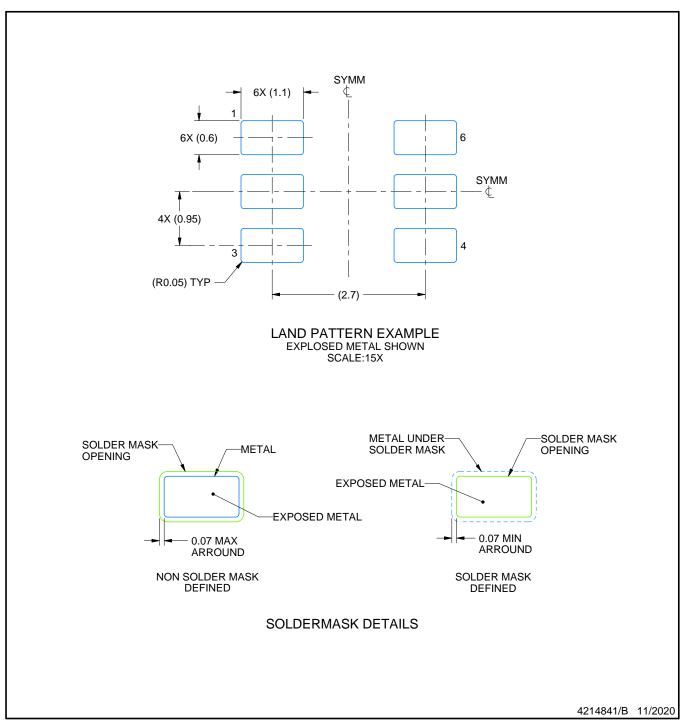


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-193.



SOT

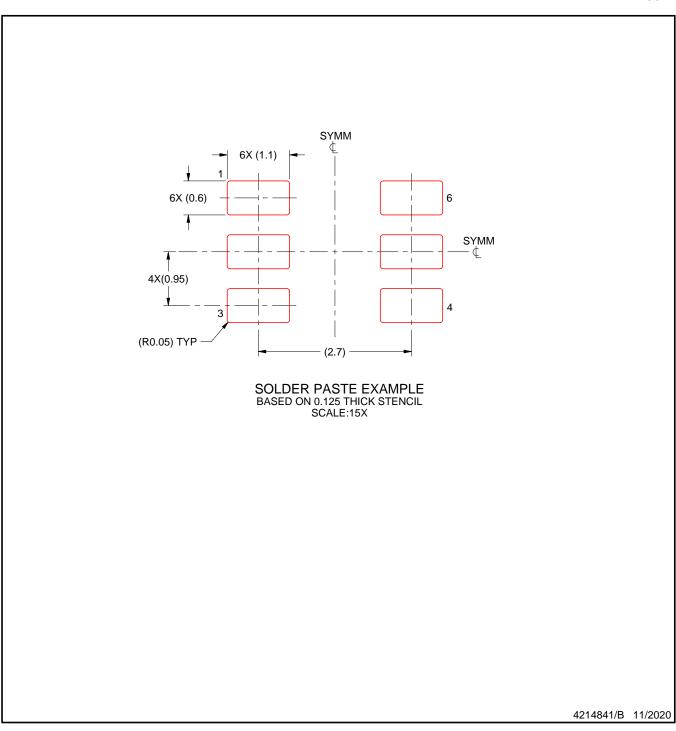


NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOT



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

 7. Board assembly site may have different recommendations for stencil design.



重要声明和免责声明

TI 均以"原样"提供技术性及可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证其中不含任何瑕疵,且不做任何明示或暗示的担保,包括但不限于对适销性、适合某特定用途或不侵犯任何第三方知识产权的暗示担保。

所述资源可供专业开发人员应用TI产品进行设计使用。您将对以下行为独自承担全部责任: (1)针对您的应用选择合适的TI产品; (2)设计、验证并测试您的应用; (3)确保您的应用满足相应标准以及任何其他安全、安保或其他要求。所述资源如有变更,恕不另行通知。TI对您使用所述资源的授权仅限于开发资源所涉及TI产品的相关应用。除此之外不得复制或展示所述资源,也不提供其它TI或任何第三方的知识产权授权许可。如因使用所述资源而产生任何索赔、赔偿、成本、损失及债务等,TI对此概不负责,并且您须赔偿由此对TI及其代表造成的损害。

TI 所提供产品均受TI 的销售条款 (http://www.ti.com.cn/zh-cn/legal/termsofsale.html) 以及ti.com.cn上或随附TI产品提供的其他可适用条款的约束。TI提供所述资源并不扩展或以其他方式更改TI 针对TI 产品所发布的可适用的担保范围或担保免责声明。

邮寄地址: 上海市浦东新区世纪大道 1568 号中建大厦 32 楼,邮政编码: 200122 Copyright © 2020 德州仪器半导体技术(上海)有限公司